



LB1991V

Three-Phase Brushless Motor Driver for Portable VCR Capstan Motors

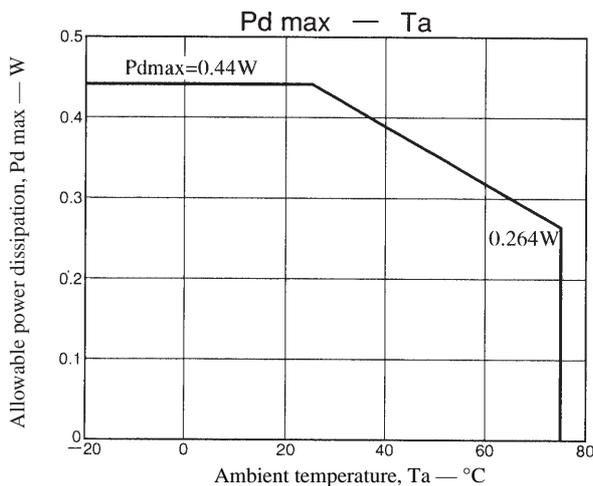
Overview

The LB1991V is a 3-phase brushless motor driver IC that is optimal for driving the capstan motor in portable VCR products.

- Speed control technique based on motor voltage and current control.
- Built-in FG comparators
- Built-in thermal shutdown circuit

Functions

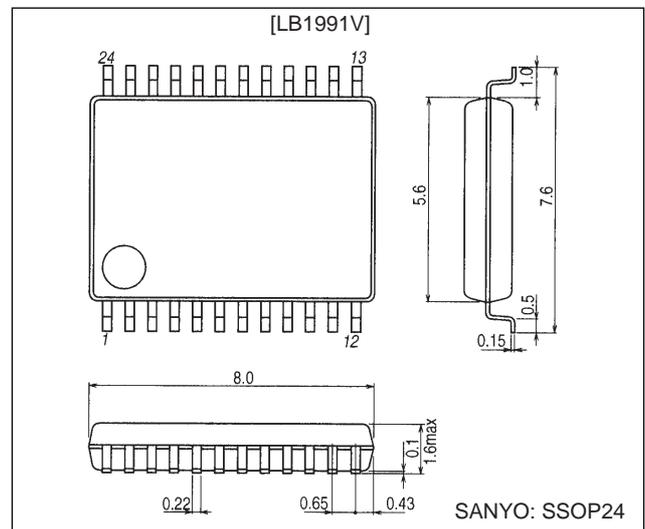
- 3-phase full-wave voltage drive technique (120° voltage-linear technique)
- Torque ripple correction circuit (overlap correction)



Package Dimensions

unit: mm

3175A-SSOP24



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC1} max		10	V
	V _{CC2} max		11	V
	V _S max		11	V
Applied output voltage	V _O max		V _S + 2	V
Maximum output current	I _O max		1.0	A
Allowable power dissipation	Pd max	Independent IC	440	mW
Operating temperature	T _{opr}		-20 to +75	°C
Storage temperature	T _{stg}		-55 to +150	°C

Allowable Operating Ranges at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC1}	V _{CC1} ≤ V _{CC2}	2.7 to 6.0	V
	V _{CC2}		3.5 to 9.0	V
	V _S		Up to V _{CC2}	V
Hall input amplitude	V _{HALL}	Between Hall effect element inputs	±20 to ±80	mVp-p

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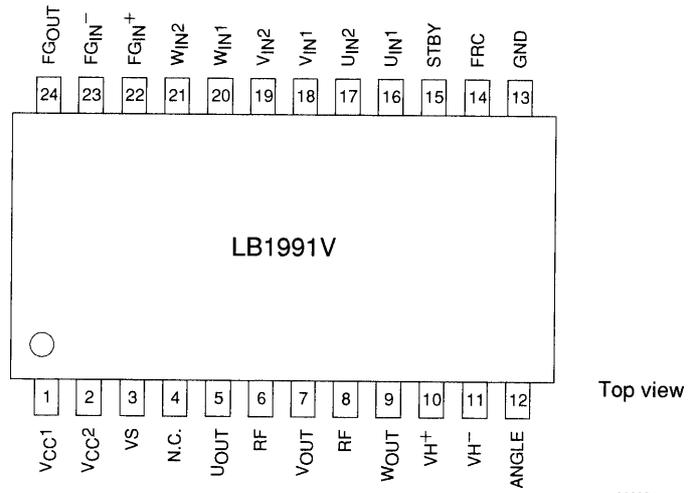
Electrical Characteristics at Ta = 25°C, V_{CC1} = 3 V, V_{CC2} = 4.75 V, V_S = 1.5 V

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
[Supply Current]						
V _{CC1} current drain	I _{CC1}	I _{OUT} = 100 mA		3	5	mA
V _{CC2} current drain	I _{CC2}	I _{OUT} = 100 mA		7.0	10.0	mA
V _{CC1} quiescent current	I _{CC1Q}	V _{STBY} = 0 V		1.5	3.0	mA
V _{CC2} quiescent current	I _{CC2Q}	V _{STBY} = 0 V			100	μA
V _S quiescent current	I _{SQ}	V _{STBY} = 0 V		75	100	μA
[VX1]						
High side residual voltage	V _{XH1}	I _{OUT} = 0.2 A	0.15	0.22	0.29	V
Low side residual voltage	V _{XL1}	I _{OUT} = 0.2 A	0.15	0.20	0.25	V
[VX2]						
High side residual voltage	V _{XH2}	I _{OUT} = 0.5 A		0.25	0.40	V
Low side residual voltage	V _{XL2}	I _{OUT} = 0.5 A		0.25	0.40	V
Output saturation voltage	V _{O(sat)}	I _{OUT} = 0.8 A, Sink + Source			1.4	V
Overlap	O.L	R _L = 39 Ω × 3, Range = 20 kΩ *2	73	80	87	%
High/low overlap difference	ΔO.L	(Average high side overlap) – (Average low side overlap) *2	–8		+8	%
[Hall Amplifiers]						
Input offset voltage	V _{HOF}	*1	–5		+5	mV
Common-mode input voltage range	V _{HCM}	Range = 20 kΩ	0.95		2.1	V
I/O voltage gain	V _{GVH}	Range = 20 kΩ	25.5	28.5	31.5	dB
[Standby Pin]						
High-level voltage	V _{STH}		2.5			V
Low-level voltage	V _{STL}				0.4	V
Input current	I _{STIN}	V _{STBY} = 3 V		25	40	μA
Leakage current	I _{STLK}	V _{STBY} = 0 V			–30	μA
[FRC Pin]						
High-level voltage	V _{FRCH}		2.5			V
Low-level voltage	V _{FRCL}				0.4	V
Input current	I _{FRGIN}	V _{FRC} = 3 V		20	30	μA
Leakage current	I _{FRCLK}	V _{FRC} = 0 V			–30	μA
[VH]						
Hall supply voltage	V _{HALL}	I _H = 5 mA, V _H (+) – V _H (–)	0.85	0.95	1.05	V
(–) pin voltage	V _H (–)	I _H = 5 mA	0.81	0.88	0.95	V
[FG Comparator]						
Input offset voltage	V _{FGOFF}		–3		+3	mV
Input bias voltage	I _{bFG}	V _{FGIN+} = V _{FGIN–} = 1.5 V			500	nA
Input bias current offset	ΔI _{bFG}	V _{FGIN+} = V _{FGIN–} = 1.5 V	–100		+100	nA
Common-mode input voltage range	V _{FGCM}		1.2		2.5	V
Output high-level voltage	V _{FGOH}	At the internal pull-up resistors	2.8			V
Output low-level voltage	V _{FGOL}	At the internal pull-up resistors			0.2	V
Voltage gain	V _{GFG}	*1		100		dB
Output current (sink)	I _{FGOS}	For the output pin low level			5	mA
[TSD]						
TSD operating temperature	T-TSD	Design target value *1		180		°C
TSD temperature hysteresis	ΔTSD	Design target value *1		20		°C

Notes: 1. Items specified as design target values in the conditions column are not tested.
2. The standard for overlap is the value as measured.

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Pin Assignment



Truth Table

	Source phase → Sink phase	Hall input			FRC
1	V → W	H	H	L	H
	W → V				L
2	U → W	H	L	L	H
	W → U				L
3	U → V	H	L	H	H
	V → U				L
4	W → V	L	L	H	H
	V → W				L
5	W → U	L	H	H	H
	U → W				L
6	V → U	L	H	L	H
	U → V				L

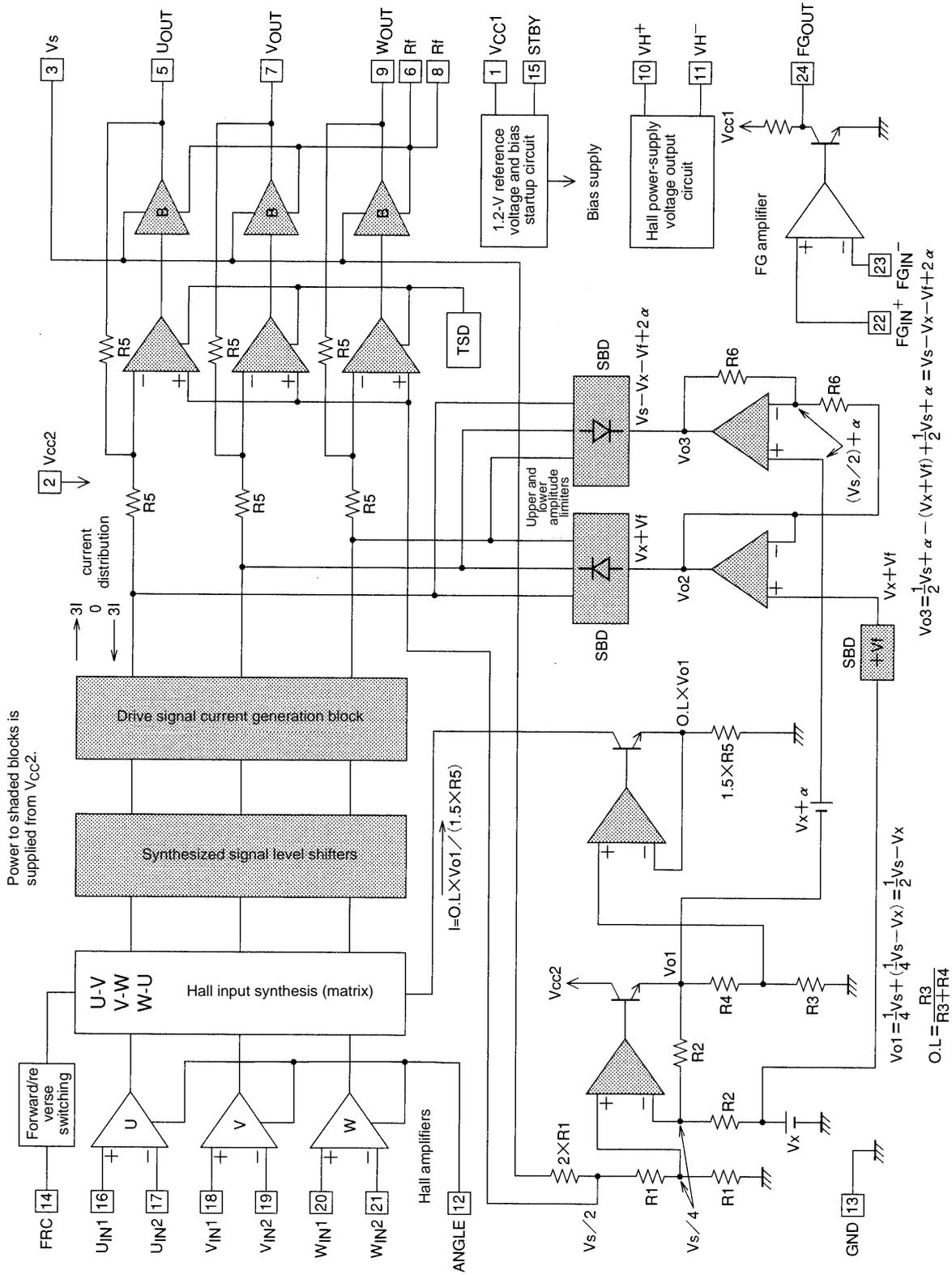
Note: The "H" entries in the FRC column indicate a voltage of 2.50 V or higher, and the "L" entries indicate a voltage of 0.4 V or lower. (When V_{CC1} is 3 V.)
 At the Hall inputs, for each phase a high-level input is the state where the (+) input is 0.02 V or higher than the (-) input. Similarly, a low-level input is the state where the (+) input is 0.02 V or lower than the (-) input.

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Pin Functions

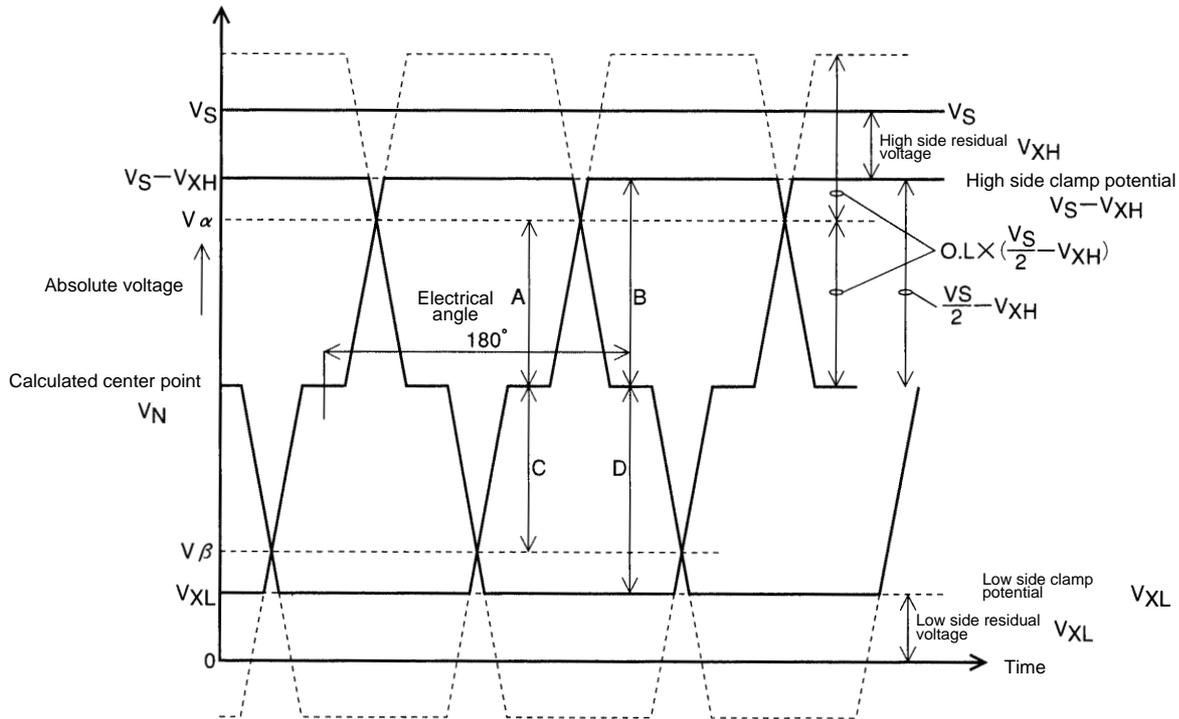
Pin No.	Pin	Equivalent circuit	Pin function
1	V _{CC1}	Supply voltage for all circuits other than the IC internal output block and the amplitude control block.	
2	V _{CC2}	Supply voltage for the IC internal output control block and the amplitude control block.	
3	V _S	Motor drive power supply. The voltage applied to this pin must not exceed V _{CC2} .	
5	U _{OUT}	U phase output	
7	V _{OUT}	V phase output (These outputs include built-in spark killer diodes.)	
9	W _{OUT}	W phase output	
6, 8	R _f	Ground for the output power transistors	
10	VH ⁺	Hall element bias voltage supply A voltage that is typically 0.95 V is generated between the VH ⁺ and VH ⁻ pins. (When I _H is 5 mA.)	
11	VH ⁻		
13	GND	Ground for circuits other than the output transistor The R _f pin potential is the lowest output transistor potential.	
14	FRC	Forward/reverse selection. Applications can select motor forward or reverse direction rotation using this pin. (This pin has hysteresis characteristics.)	
15	STBY	Selects the bias supply for all circuits other than the FG comparators. The bias supply is cut when this pin is set to the low level.	
16	U _{IN1}	U phase Hall element input	
17	U _{IN2}	The logic high level is the state where the IN+ voltage is greater than the IN- voltage.	
18	V _{IN1}	V phase Hall element input	
19	V _{IN2}	The logic high level is the state where the IN+ voltage is greater than the IN- voltage.	
20	W _{IN1}	W phase Hall element input	
21	W _{IN2}	The logic high level is the state where the IN+ voltage is greater than the IN- voltage.	
12	ANGLE	Hall input/output gain control. The gain is controlled by the resistor connected between this pin and ground.	
22	FG _{IN+}	FG comparator noninverting inputs. There is no internally applied bias.	
23	FG _{IN-}	FG comparator inverting inputs. There is no internally applied bias.	
24	FG _{OUT}	FG comparator outputs. There is an internal 20-kΩ resistor load.	

Block Diagram



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Overlap Generation and Calculation Method



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[Overlap Generation]

Since the voltage generated in the amplitude control block is, taking the center point as the reference, $2 \times \langle \text{overlap} \rangle \times (1/2 V_S - V_X)$ on one side, the intersection point of the waveform will be $\langle \text{overlap} \rangle \times (1/2 V_S - V_X)$ from the center point.

To clamp that waveform at $(1/2 V_S - V_X)$ referenced to the center point the overlap must be:

$$A/B \times 100 = \langle \text{overlap} \rangle \times 100 (\%)$$

[Overlap Calculation]

• High side overlap

$$\text{Calculated center point: } V_N = \frac{(V_S - V_{XH} - V_{XL})}{2} + V_{XL} = \frac{(V_S - V_{XH} + V_{XL})}{2}$$

Since $A = V_\alpha - V_N$, $B = V_S - V_{XH} - V_N$, the high side overlap will be:

$$\langle \text{overlap} \rangle = \frac{A}{B} = \frac{V_\alpha - ((V_S - V_{XH} + V_{XL})/2)}{V_S - V_{XH} - ((V_S - V_{XH} + V_{XL})/2)} \times 100 (\%)$$

Which can be calculated as:

$$= \frac{2V_\alpha - (V_S - V_{XH}) - V_{XL}}{(V_S - V_{XH}) - V_{XL}} \times 100 (\%)$$

• Low side overlap

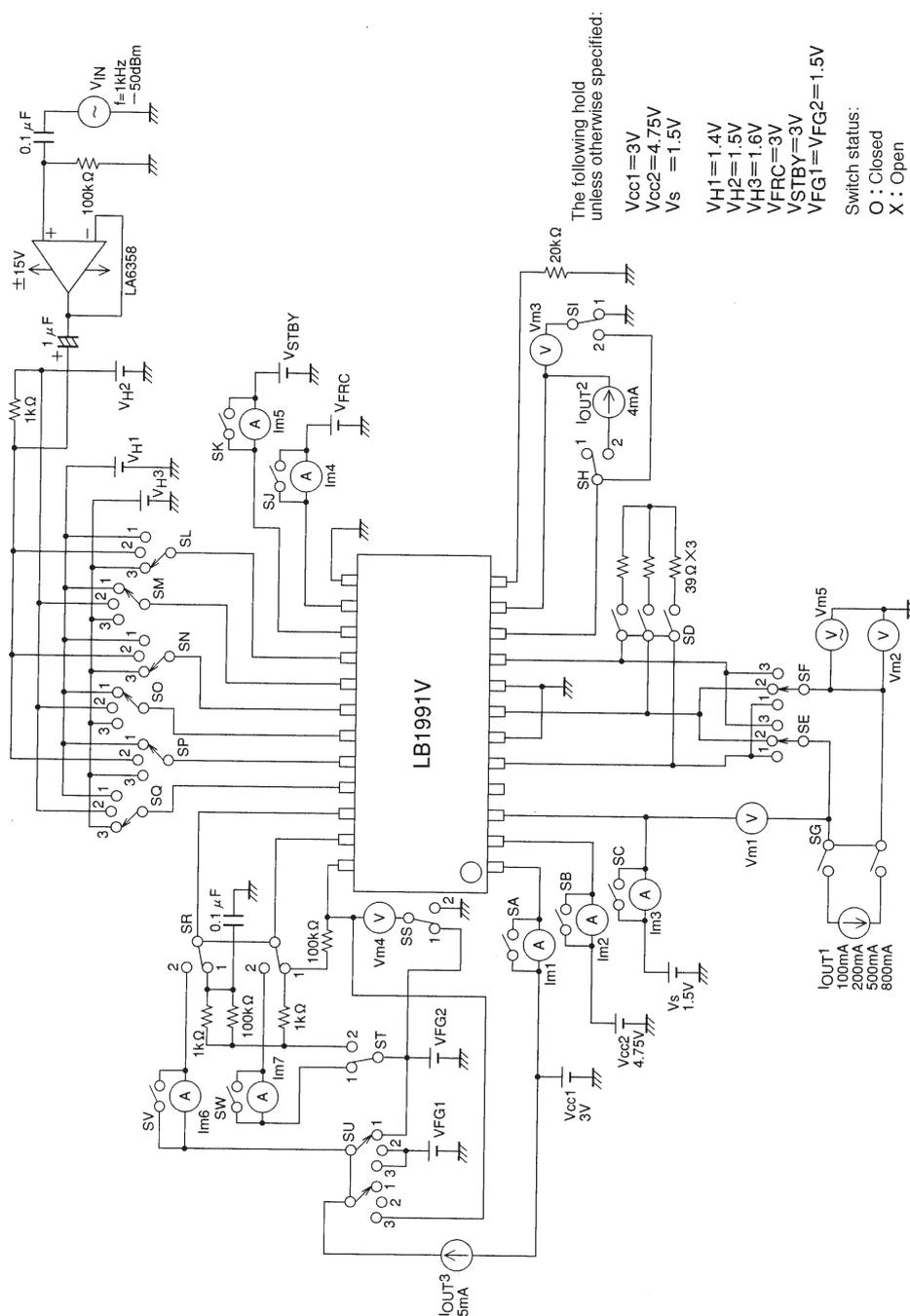
Since $C = V_N - V_\beta$, and $D = V_N - V_{XL}$, the low side overlap will be:

$$\langle \text{overlap} \rangle = \frac{C}{D} = \frac{((V_S - V_{XH} + V_{XL})/2)}{((V_S - V_{XH} + V_{XL})/2) - V_{XL}} \times 100$$

Which can be calculated as:

$$= \frac{(V_S - V_{XH}) - V_{XL} - 2V_\beta}{(V_S - V_{XH}) - V_{XL}} \times 100 (\%)$$

Test Circuit



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